NSN 5961-00-904-0803

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-904-0803 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-33 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 25.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 0.00001 milliamperes zero-gate-voltage source current preset all transistor **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 8 uninsulated wire lead **Specification Data:** 80131-release4644 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0